



IR Receiver Modules for Remote Control Systems

Description

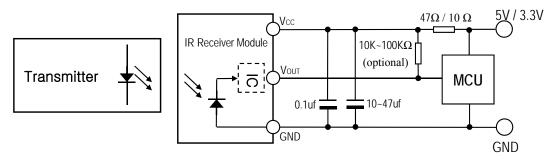
The FM-71 ———-5DN is miniaturized receiver for infrared remote control system.

The PIN Photodiode and preamplifier are assembled on lead frame. The epoxy package is designed as IR filter. The module has excellent performance even in disturbed ambient light application and provides protection against uncontrolled output pulses.

Features

- Transfer Mold Package.
- Supply Voltage Range: 2.7V to 5.5 V
- Supply Current: 0.4mA
- Epoxy IR filter characteristic: 940nm
- Maximum interference safety against optical and electrical disturbance.
- Internal filter for a high frequency lighting fluorescent lamp.
- Internal Pull-Up output.
- Meet RoHS

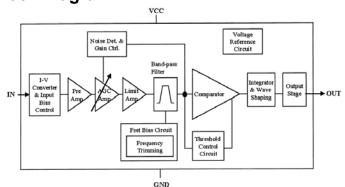
Application Circuit



R-C filter recommended to suppress power supply disturbances.

R-C filter should be connected closely between Vcc pin and GND pin.

Block Diagram



B.P.F Center Frequency

Model No.	Carrier Frequency (fo)
FM-7136□□-5DN	36 KHz
FM-7138□□-5DN	38 KHz
FM-7140□□-5DN	40 KHz
FM-7156□□-5DN	56 KHz





Suitable Data Format

NEC code	•	RCMM code		Sony 12-bit code	•
RC5 code	•	RECS-80 code \diamondsuit Sony 15-bit		Sony 15-bit code	•
RC6 code	•	R-2000 code		Sony 20-bit code	\Diamond
Grundig code	•	RCA code	♦ High data rate code		\Diamond
Sharp code	•	Zenith code	•	Disturbance suppression	•

◆ : Suitable for this IR code ; ♦ : Not recommended

The data signal should full-fill the following condition:

- Carrier frequency should be close to center frequency of the band-pass.
- Burst length should be 300us/burst or longer.
- After each burst a gap time of at least 300us is necessary.
- The data format should not make a continuous signal transmission.
- There must be a Signal Gap Time (longer than 23 ms) at least each 100 ms, or each data command.

Absolute Maximum Ratings

(Ta = 25°C)

Parameter	Symbol	Ratings	Unit
Supply Voltage	Vcc	6.5	V
Supply Current	Icc	3.0	mA
Output Current	Isink	2.5	mA
Operating Temperature	Topr	-20 ~ +80	°C
Storage Temperature	T _{stg}	-30 ~ +85	°C
Soldering Temperature	T _{sd}	260°C, Max 5 sec	°C

Electro-optical Characteristics

(Ta = 25°C)

elocato optical characteristics							
Parameter	Symbol		Min.	Тур.	Max.	Unit	Conditions
Supply Current	ICC		0.25	0.37	0.50	mA	No signal
Output Voltage	Voh		Vcc-0.5	-	-	V	
	Vol		-	0.2	0.4	V	
Peak Wave Length	λр		-	940	-	nm	
Internal Pull-up Resistor	Rpul		-	40	-	kΩ	
BPF Bandwidth	fвw		2.5	4.5	6.5	KHz	-3dB Bandwidth
Arrival Distance		±0°	20	-	-	m	
	L	±30°	15	-	-	m	Fig 1,2,3
		±45°	10	-	-	m	
Output Pulse width	Трw		400	600	800	us	Burst Wave =600us
							Period = 1.2ms

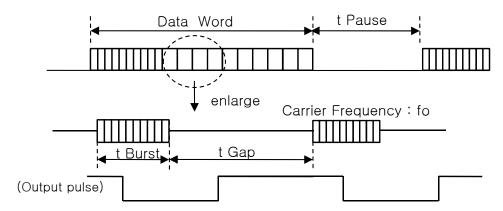
Note:

- 1) Arrival Distance Effected by Environment
- 2) While the device is operational across the temperature range, functionality will vary with temperature. Specifications are stated only at 25°C unless otherwise noted.
- 3) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.



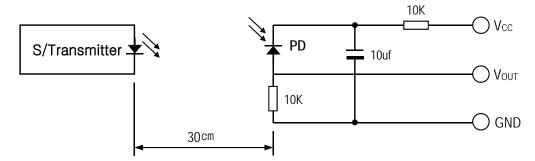


[Fig.1] Data Signal diagram



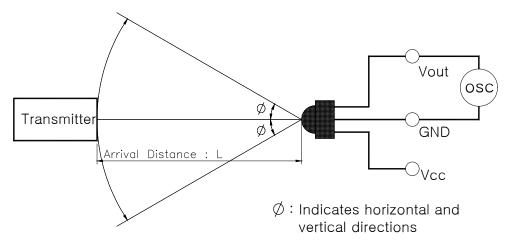
		Min
t Burst	(Length of a burst in pulses of the carrier frequency)	210us
t Gap	(Signal gap time between two burst in pulses of carrier)	320us
t Pause	(Data pause between two data words)	22ms

[Fig.2] Transmitter



* The specifications shall be satisfied under the following conditions. The standard transmitter shall be specified of the burst wave form adjusted to Vout 200mVp-p upon Po measuring circuit Standard Transmitter

[Fig.3] Test condition of arrival distance



[Measurement condition for arrival distance]

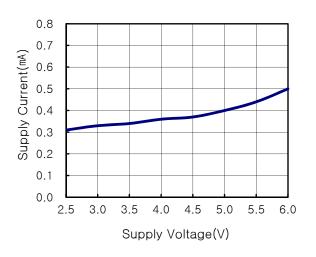
Ambient light source: Detecting surface illumination shall be irradiate 200±50Lux under ordinary white fluorescence lamp without high frequency lighting



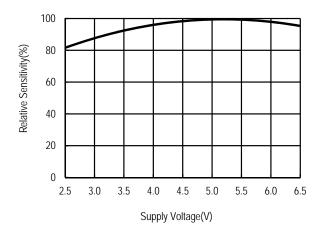


Electrical/Optical Characteristics

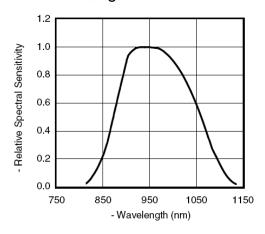
[Fig.4] Supply Current vs. Voltage



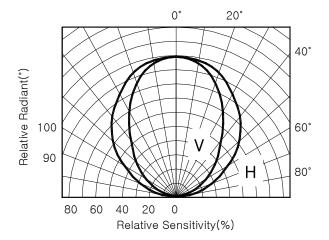
[Fig.6] Sensitivity vs. Supply Voltage



[Fig.5] Relative Spectral Sensitivity vs. Wavelength



[Fig.7] Directivity (Horizontal/Vertical)



ESD Test Results

Parameter	Conditions	Specification	Results
Machine Model	C=200pF R=0Ω	Min ±200V	>±200V
	C=100pf R=1.5KΩ	Min ±2000V	>±2000V





